This paper reports recent progress in the patterning of non-linear optical crystals on the glass surface by laser irradiation. Two techniques for the writing of crystal lines have been developed, i.e., rare-earth (samarium) atom heat processing and transition metal atom heat processing, in which a continuous wave Nd:YAG laser (wavelength: $\lambda = 1064$ nm) is irradiated to the glasses containing rare-earth (RE: Sm$^{3+}$, Dy$^{3+}$) ions or transition metal (TM: Ni$^{2+}$, Fe$^{2+}$, V$^{4+}$) ions. The writing of crystal lines such as $\beta$-BaB$_2$O$_4$, Sm$_2$B$_5$xBO$_{15}$, and Ba$_2$TiGe$_2$O$_8$ showing second harmonic generations has been successful. It is clarified from the azimuthal dependence of second harmonic intensity and polarized micro-Raman scattering spectra that crystal lines consist of highly oriented crystals along the crystal line growth direction. It is also possible to write two-dimensional crystal bending or curved lines by just changing the laser scanning direction. The mechanism of the laser-induced crystallization has been proposed.

**I. Introduction**

Glasses having high transparency, high chemical durability, excellent thermal and electrical properties are key materials in microelectronics, optics, and optical fiber technology. Micro-fabrication of glass materials has found increasingly more applications in optoelectronics, telecommunications, and photonic devices such as optical gratings and waveguides, and laser irradiation to glass has received considerable attention as a new tool of spatially selected micro-fabrication.$^{1-5}$ For instance, a permanent change of refractive index can be induced in Ge-based glasses by irradiation of a continuous wave Nd:YAG or excimer lasers, and structural modifications are refractive index changes.

On the other hand, it is well recognized that glass is the material that has an inversion symmetry, in principle, yielding no second-order optical non-linearity or ferroelectricity. This has generally brought glass materials only to passive usage like optical glass fibers, while second-order optical non-linearity is the property absolutely required for active applications such as electro-optic switching and wavelength conversion. From this point of view, it is of importance and interest to design spatially selected patterning of non-linear optical/ferroelectric crystals in glass.

The present authors’ group succeeded in writing non-linear optical crystal dots and lines in Sm$_2$O$_3$ (Dy$_2$O$_3$)-containing glasses by irradiation of a continuous wave (cw) Nd:YAG laser with a wavelength of $\lambda = 1064$ nm. This new technique has been called "rare-earth (samarium) atom heat processing" (designated here as REAH [SAAH] processing) and has been applied to various glass systems.$^{6-8}$ It should be emphasized that Nd:YAG laser is very conventional compared with other kinds of lasers such as ultraviolet or femtosecond pulsed laser. A key point in REAH processing is a combination of rare-earth ions and Nd:YAG laser with $\lambda = 1064$ nm, and it is prerequisite to prepare glasses with some amounts (~ more than 8 mol%) of Sm$_2$O$_3$ (or Dy$_2$O$_3$) in order to increase the temperature sufficiently in the laser-irradiated region. Considering the concept of REAH processing, other combinations would be possible for laser-induced crystallization in glass.$^{19,20}$ For instance, the present authors’ group$^{20}$ found that the combination of transition (TM) metal ions such as Fe$^{2+}$, Ni$^{2+}$, and V$^{4+}$ and cw Nd:YAG laser ($\lambda = 1064$ nm) induces effectively crystallization in glasses with a small amount (~ 1 mol%) of TM ions. This technique has been proposed to be called "transition metal atom heat (TMAH) processing."

In this paper, we report recent progress in the patterning of crystal lines showing second-order optical non-linearities on the glass surface by using REAH (SAAH) and TMAH processing. The mechanism of the laser-induced crystallization has also been discussed. It should be emphasized that studies on the patterning (writing) of crystal lines in glass by laser irradiation techniques except REAH and TMAH processing, are a few.$^{21,22}$

**II. REAH/TMAH Processing**

In rare-earth atom heat processing, cw Nd:YAG lasers with $\lambda = 1064$ nm are irradiated onto glasses containing Sm$_2$O$_3$ (or...
Dy$_2$O$_3$). As Sm$^{3+}$ (or Dy$^{3+}$) has an absorption band at around 1064 nm, some amounts of cw Nd:YAG laser are absorbed by Sm$^{3+}$ in glass through f-f transitions ($^2F_{5/2} \rightarrow ^4H_{5/2}$). For example, 10Sm$_2$O$_3$–40BaO–50B$_2$O$_3$ glass has an absorption coefficient of $\alpha = 7.9$ cm$^{-1}$ at $\lambda = 1064$ nm.\textsuperscript{10} The electronic energy levels of Sm$^{3+}$ and Dy$^{3+}$ are shown in Fig. 1. As the main relaxation mechanism from $^6F_{5/2}$ to $^4H_{5/2}$ is non-radiative, the YAG laser energy absorbed by Sm$^{3+}$ in glass is transferred to the lattice system (lattice vibrations) through electron–phonon coupling. That is, the surrounding of Sm$^{3+}$ is heated through such a non-radiative relaxation process. Consequently, if the temperature of the laser-irradiated region becomes higher than the glass transition or crystallization temperatures of a given glass, structural modification such as a refractive index change or crystallization could be induced. As the heat dissipation from the laser-irradiated region to the surrounding glass medium is expected to occur rapidly, it would be necessary to irradiate laser continuously to maintain high temperatures (greater than the crystallization temperature) and thus to use continuous-wave type lasers for laser-induced crystallization in glass. It should be emphasized that, in the case of a nanopulse Nd:YAG laser with $\lambda = 1064$ nm, no crystallization has been induced in our various studies.\textsuperscript{6–18,23}

It is well known that transition metal ions such as Ni$^{2+}$ and Fe$^{2+}$ in glass give rise to absorption bands in the visible and infra-red spectral regions. As an example, the optical absorption spectra at room temperature for NiO (1 mol%)-doped 33.3BaO–16.7TiO$_2$–50GeO$_2$ glass are shown in Fig. 2. The absorption bands around 300–600 and 750–1400 nm are attributed to the $^3A_2 \rightarrow ^3T_1$ and $^3A_2 \rightarrow ^3T_2$ transition in six-fold Ni$^{2+}$ ions,\textsuperscript{24} respectively. The absorption coefficient at 1064 nm is $\alpha = 6.01$ cm$^{-1}$ for this NiO-doped glass. It should be pointed out that the value of $\alpha = 6.01$ cm$^{-1}$ in the glass containing only 1 mol% NiO is comparable with those for the glasses with 10 mol% Sm$_2$O$_3$ content.\textsuperscript{10} It is, therefore, expected that Nd:YAG laser-irradiated spots in NiO-doped glasses would be heated, although the non-radiative relaxation phenomenon of Ni$^{2+}$ ions in glasses, in particular at the $^3A_2 \rightarrow ^3T_2$ transition, has not been clarified quantitatively. Indeed, we found that TM ions such as Fe$^{2+}$, Ni$^{2+}$, and V$^{4+}$ act as effective atom heaters, consequently, inducing the crystallization in glass by Nd:YAG laser irradiation.\textsuperscript{20} Inoue et al.\textsuperscript{25} examined the phenomenon of the refractive index change in CoO-doped (2 mol%) TeO$_2$-based glasses due to the pulsed laser irradiation with $\lambda = 523$ nm and proposed that the refractive index change (not crystallization) is derived from the change of the fictive temperature of the glasses. Their study also suggests that even in the TMAH processing developed by our research group, the use of cw (not pulsed) Nd:YAG laser is required to induce crystallization.

### III. Experimental Procedure

Glasses such as 10Sm$_2$O$_3$–35Bi$_2$O$_3$–55B$_2$O$_3$, 10Sm$_2$O$_3$–40BaO–50B$_2$O$_3$, and 33.3BaO–16.7TiO$_2$–50SiO$_2$ (mol%) were prepared by a conventional melt quenching method. Details of the base glass preparation have been described elsewhere.\textsuperscript{6–18,20} The glass transition, $T_g$, crystallization onset, $T_x$, and crystallization peak, $T_{p}$, temperatures were determined using differential thermal analyses (DTA) at a heating rate of 10 K/min. The quenched glasses were annealed at around $T_g$ to release internal stress and then polished mechanically to obtain a mirror finish with CeO$_2$ powders. A cw Nd:YAG laser with $\lambda = 1064$ nm was irradiated to the polished surface of the glasses. The laser beam was focused on the surface of the glasses using an objective lens (magnification 20 or 60) and the sample stage was automatically moved during laser irradiations to construct line patterns. Crystal lines written by Nd:YAG laser irradiation were observed with a polarization optical microscope. The second harmonic intensity of crystal lines was measured by using a fundamental wave of Q-switched pulse Nd:YAG laser with $\lambda = 1064$ nm as a laser source, in which linearly polarized fundamental laser beams were introduced into crystal lines perpendicularly, and the azimuthal dependence of second harmonic generation (SHG) signals was measured by rotating the sample against incident lasers. Polarized micro-Raman-scattering spectra at room temperature for crystal lines written by Nd:YAG laser irradiation were measured with a laser microscope (Tokyo Instruments Co., Tokyo, Japan; Nanofinder) operated at Ar$^+$ (488 nm) laser.

### IV. Results and Discussion

#### (1) Writing and Features of Crystal Lines

As the YAG laser energy absorbed by Sm$^{3+}$ in glass is transferred to the lattice vibration energy, the temperature of the laser-irradiated region is sensitive to the amount of Sm$_2$O$_3$ in a given glass. Under the conditions of the cw Nd:YAG laser power of $\sim$1 W, Sm$_2$O$_3$ contents of over around 8 mol% are needed to induce structural modifications such as refractive index change and crystallization.\textsuperscript{6–18} As an example, the polarization optical micrographs for the sample obtained by Nd:YAG laser irradiation in 10Sm$_2$O$_3$–35Bi$_2$O$_3$–55B$_2$O$_3$ glass are shown in Fig. 3, where a Nd:YAG laser with powers of $P = 0.6–0.8$ W and a scanning speed of $S = 10$ mm/s was irradiated on the glass surface.\textsuperscript{17} At a laser power of $P = 0.6$ W, it was found from micro-Raman scattering spectrum that the line is not crystal, but glass, indicating the formation of refractive index change. In $P = 0.66$ W, a homogeneous crystal line with a uniform width of $\sim$5 mm was clearly written. When the laser power is higher than 0.8 W, crystals with a rough morphology grow as shown in Fig. 3. Although the mechanism of the formation of these rough morphologies is unclear, the results suggest the instability of the crystal growth front. That is, the crystal growth behavior similar to the so-called Mullins–Sekerka
instability for the shape of a moving planar liquid–solid interface might occur even in the Nd:YAG laser-induced crystallization in glass. As 10Sm<sub>2</sub>O<sub>3</sub>–35Bi<sub>2</sub>O<sub>3</sub>–55B<sub>2</sub>O<sub>3</sub> glass has values of \( T_g \approx 474^\circ \text{C} \) and \( T_x \approx 574^\circ \text{C} \), it is considered that the laser-irradiated regions with powers of \( 4 \pm 0.65 \) W would be heated up to temperatures higher than \( 580^\circ \) C. The crystalline phase in the laser-irradiated region with a power of 0.66 W shown in Fig. 3 is \( \beta'\)-Sm<sub>2</sub>(MoO<sub>4</sub>)<sub>3</sub>, which is a non-linear optical crystal showing a strong SHG. Indeed, we can observe SHGs from the lines written by YAG laser irradiation.

Crystal lines consisting of other non-linear optical crystalline phases have been successfully written in glasses using an REAH processing, e.g., \( \beta'\)-BaB<sub>2</sub>O<sub>4</sub> crystal lines in Sm<sub>2</sub>O<sub>3</sub> (Dy<sub>2</sub>O<sub>3</sub>)<sub>5</sub>–BaO–B<sub>2</sub>O<sub>3</sub>, KSm(PO<sub>4</sub>)<sub>3</sub> crystal lines in K<sub>2</sub>O–Sm<sub>2</sub>O<sub>3</sub>–P<sub>2</sub>O<sub>5</sub>, \( \beta'\)-Sm<sub>2</sub>(MoO<sub>4</sub>)<sub>3</sub> crystal lines in Sm<sub>2</sub>O<sub>3</sub>–MoO<sub>3</sub>–B<sub>2</sub>O<sub>3</sub>, and Sr<sub>0.5</sub>Ba<sub>0.5</sub>Nb<sub>2</sub>O<sub>6</sub> crystal line in Sm<sub>2</sub>O<sub>3</sub>–SrO–BaO–Nb<sub>2</sub>O<sub>5</sub>–B<sub>2</sub>O<sub>3</sub> glasses.

The polarization optical micrograph for the cross-section of a crystal line written by Nd:YAG laser irradiation \( (P = 0.42 \text{ W}, S = 10 \mu \text{m/s}) \) in 21.2Sm<sub>2</sub>O<sub>3</sub>–63.75MoO<sub>3</sub>–15B<sub>2</sub>O<sub>3</sub> glass (mol%) with \( T_g = 528^\circ \text{C} \) and \( T_p = 572^\circ \text{C} \) is shown in Fig. 4. It was confirmed from the micro-Raman scattering spectrum that this crystal line consists of the non-linear optical/ferroelectric \( \beta'\)-Sm<sub>2</sub>(MoO<sub>4</sub>)<sub>3</sub> crystalline phase.\textsuperscript{16} It is seen that \( \beta'\)-Sm<sub>2</sub>(MoO<sub>4</sub>)<sub>3</sub> crystals grow deeply into the interior of the glass during laser scanning and a swelling occurs at the surface. The formation of swells suggests that a liquid phase is locally formed by Nd:YAG laser irradiation.

As one demonstration for the techniques developed in our group, a famous ground picture (bird) in Nazca (Peru in South America) was designed on the surface of 8Sm<sub>2</sub>O<sub>3</sub>–37Bi<sub>2</sub>O<sub>3</sub>–55B<sub>2</sub>O<sub>3</sub> glass using Nd:YAG laser irradiation \( (P = 0.8–0.9 \text{ W}, S = 4 \mu \text{m/s}) \), and the result is shown in Fig. 5. Although the designed picture has various bending angles, a patterning of a bird showing SHGs has been successful.\textsuperscript{18}

(2) Quality of Crystal Lines

The quality of the crystal lines written by Nd:YAG laser irradiation is very important for application to light control photonic devices. In order to examine the quality of the crystal lines, \( \beta'\)-BaB<sub>2</sub>O<sub>4</sub> (the so-called \( \beta'\)-BBO) crystal lines were selected for the following reasons: \( \beta'\)-BBO is one of the most important non-linear optical crystals in laser optics, and its crystal structure is well known. Its remarkable features include a large second-order optical non-linearity of \( d_{22} = 2.22 \text{ pm/V} \) and a wide optical transmittance range (190–3500 nm). A crystal-line array of 15 lines was prepared in 10Sm<sub>2</sub>O<sub>3</sub>–40BaO–50B<sub>2</sub>O<sub>3</sub> glass by scanning Nd:YAG laser \( (P = 0.6 \text{ W}) \) irradiation with a speed of \( S = 5 \mu \text{m/s} \), where the length of each crystal line is 10 mm and the distance between the lines (pitch) is 50 \( \mu \text{m} \).\textsuperscript{10,14} The polarization optical micrograph for such crystal lines is shown in Fig. 6. The XRD pattern for such a crystal-line array is shown in Fig. 7. The peak corresponding to the (110) plane in \( \beta'\)-BBO is confirmed, indicating that \( \beta'\)-BBO crystals are highly oriented in the lines.

The azimuthal dependence of SHG signals for \( \beta'\)-BBO crystal lines is shown in Fig. 8. The maximum SH intensities are observed at the rotation angles of \( \sim 0^\circ \) and \( 180^\circ \), and the minimum intensities are located at \( 90^\circ \) and \( 270^\circ \). The same experiment was
carried out for the $\gamma$-cut $\beta$-BBO single crystal obtained commercially, and the results are also shown in Fig. 8. The $\gamma$-cut plane in a $\beta$-BBO single crystal corresponds to the (110) plane. It is clear that the azimuthal dependence of SHG signals for $\beta$-BBO crystal lines written by Nd:YAG laser irradiation in the glasses is almost the same as that for a commercially available $\gamma$-cut $\beta$-BBO single crystal. We also found that polarized micro-Raman spectra for $\beta$-BBO crystal lines are almost the same as those for the $\gamma$-cut $\beta$-BBO single crystal. These results strongly suggest that the crystal lines written by Nd:YAG laser irradiation might be $\beta$-Ba$_2$B$_4$O$_7$ single crystals with a c-axis orientation along the laser scanning direction.

The polarization optical micrograph for the sample obtained by Nd:YAG laser irradiation ($P = 0.85$ W, $S = 5$ $\mu$m/s) in NiO-doped (1 mol%) 33.3BaO–16.7TiO$_2$–50GeO$_2$ glass (designated here as BTG50 glass) is shown in Fig. 9. Structural modification with a width of approximately 5 $\mu$m is clearly observed in the laser-irradiated region. From the micro-Raman-scattering spectra for the laser-irradiated region, it is demonstrated that fresnoite-type Ba$_2$TiGe$_2$O$_8$ crystals are formed. Furthermore, it was confirmed from the azimuthal dependence of SHG signals that Ba$_2$TiGe$_2$O$_8$ crystals are highly oriented along the laser scanning direction. The BTG50 glass has values of $T_g = 670$ and $T_r = 780$ °C, and it is, therefore, considered that the temperature of the Nd:YAG laser-irradiated region in NiO-doped BTG50 glass would increase at least up to around 800°C. In other words, a small addition of 1 mol% NiO is effective in the heating of glasses by cw Nd:YAG laser irradiation. It is extremely important to determine the incorporation amount of Ni$^{2+}$ into Ba$_2$TiGe$_2$O$_8$ crystals. The clear observation of SHG (green light of 532 nm) from Ba$_2$TiGe$_2$O$_8$ crystal lines suggests that the incorporation of Ni$^{2+}$ into Ba$_2$TiGe$_2$O$_8$ crystal lines might be small. If a large amount of Ni$^{2+}$ is incorporated, a clear SHG would not be observed because of a strong absorption of the SH waves with $\lambda = 532$ nm due to Ni$^{2+}$.

Similar experiments were carried out for Fe$_2$O$_3$- and V$_2$O$_5$-doped (0.3–1 mol%) BTG50 glasses, and it was found that highly oriented Ba$_2$TiGe$_2$O$_8$ crystal lines are written by Nd:YAG laser irradiations. It is, therefore, concluded that the absorption of the d–d transition of TM ions for a Nd:YAG laser with $\lambda = 1064$ nm is effective in inducing crystallization of glasses. It is known that fresnoite-type Ba$_2$TiGe$_2$O$_8$ crystals reveal interesting dielectric and optical features such as piezoelectricity and ferroelectricity, and in addition, the present authors’ group reported that the surface-crystallized glasses consisting of Ba$_2$TiGe$_2$O$_8$ crystals show the large second-order optical non-linearity comparable with that of a LiNbO$_3$ single crystal. It is, therefore, of interest to write Ba$_2$TiGe$_2$O$_8$ crystal lines on the glass surface by Nd:YAG laser irradiation.

### (3) Writing of Bending Crystal Lines

Usually, optical waveguides such as ferroelectric Ti-doped LiNbO$_3$ single crystals have been fabricated by constructing curved lines (Y-shaped divergence) with different refractive indices in substrates. It is, therefore, of extreme importance to establish techniques for the writing of crystal-curved lines in glass mate-

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**Fig. 6.** Polarization optical micrograph for the crystal straight lines written by Nd:YAG laser irradiation in 10Sm$_2$O$_3$–40BaO–50B$_2$O$_3$ glass. The laser power was 0.6 W and the scanning speed was 5 $\mu$m/s.

**Fig. 7.** X-ray diffraction (XRD) pattern for a crystal line array obtained by YAG laser irradiation in 10Sm$_2$O$_3$–40BaO–50B$_2$O$_3$ glass. The XRD powder pattern for the crystallized glass obtained by heat treatment in an electric furnace is also shown. The crystalline phase is assigned to $\beta$-Ba$_4$B$_7$O$_{12}$.

**Fig. 8.** Azimuthal dependence of second harmonic generation signals for crystal lines written by Nd:YAG laser irradiation in Sm$_2$O$_3$–Dy$_2$O$_3$–BaO–B$_2$O$_3$ glasses. The data for a commercially available $\beta$-BaB$_2$O$_4$ single crystal are also shown.

**Fig. 9.** Polarization optical micrograph for the line written by Nd:YAG laser irradiation in NiO-doped (1 mol%) 33.3BaO–16.7TiO$_2$–50GeO$_2$ glass.
The curved crystal lines shown in Fig. 11 consist of Sm$_3$Bi$_{1-x}$BO$_3$ crystals. It should be emphasized that any appreciable changes such as structural damages have not been observed even at the bending point.

The polarized micro-Raman scattering spectra for the part located at the behind position of $\sim 100 \mu$m from the bending point in the bending crystal line (angle: 30°) are shown in Fig. 11, where the angle between the polarized direction of incident laser and the line growth direction was changed from parallel to perpendicular. In these observations, for instance, the relation with the angle of 60° is designated here as B|P60°. In the Raman scattering spectra shown in Fig. 11, sharp peaks are observed at 562, 633, and 925 cm$^{-1}$. These peaks are assigned to Sm$_3$Bi$_{1-x}$BO$_3$ crystals showing SHGs. Unfortunately, the crystal structure of the Sm$_3$Bi$_{1-x}$BO$_3$ phase has not been clarified at this moment. As can be seen in Fig. 11, the intensity of the peaks at around 1200 cm$^{-1}$ changes largely depending on the angle between the polarized direction of incident laser and the line growth direction. If the crystal line consists of a random assembly of Sm$_3$Bi$_{1-x}$BO$_3$ crystals and is thus a polycrystalline line, almost similar Raman scattering spectra would be obtained irrespective of the angle between the polarized direction of incident laser and the line growth direction. That is, the data shown in Fig. 11 suggest that Sm$_3$Bi$_{1-x}$BO$_3$ crystals in the bending point are highly oriented, as already proposed for the straight crystal lines.

Similar observations were made for the part at the before position of $\sim 100 \mu$m from the bending point in the bending crystal line, where the notations such as A|P60° have been used. It was found that the polarized Raman spectra (i.e., A|P0°, A|P30°, A|P60°, and A|P90°) at the before position are almost the same as those (Fig. 11) at the behind position. That is, it is suggested that the line after bending also consists of Sm$_3$Bi$_{1-x}$BO$_3$ crystals with a high orientation. The relative (normalized) intensities of the peaks at around 1200 cm$^{-1}$ against the peaks at 925 cm$^{-1}$ for the relations of B|P30° and A|P30° are shown in Fig. 12. It can be seen that both relations show the same data. Similar behaviors were observed for the relations of B|P0° and A|P0°, B|P60° and A|P60°, and B|P90° and A|P90°. The data shown in Fig. 12 strongly suggest that the crystal plane of Sm$_3$Bi$_{1-x}$BO$_3$ crystals to the crystal growth direction might be maintained at positions of over $\sim 100 \mu$m from the bending point even after a change in the laser scanning direction. The crystal structure and growth direction at just the bending point are of particular interest, but at this moment we do not have any conclusive data.

The light ($\lambda = 632.8$ nm) transmissions were confirmed for a crystal line (length: 850 μm) with two bending angles of 30° written by Nd:YAG laser irradiation in 8Sm$_3$O$_7$–37Bi$_2$O$_5$–55B$_2$O$_3$ glass, where significant light scattering losses were not observed at the bending points. These results demonstrate that two-dimensional, highly oriented crystal-curved lines with bending or sine-curved shapes can be successfully written in Sm$_3$O$_7$–Bi$_2$O$_5$–B$_2$O$_3$ glasses using REAH (SAAH) processing. If the crystal line consists of a random assembly of crystals, a large scattering of light would occur at the interface between crystals. The quantitative evaluation on the light transmission loss and mode in the highly oriented crystal lines is now under study.

(4) Mechanism of Laser-Induced Crystallization

In the laser-induced crystallization of glass using Nd:YAG laser irradiation, there are two prominent features compared with usual crystallization of glass using an electric furnace: the first one is the volume expansion in the laser-irradiated region, and the second one is the highly oriented crystal growth along the laser scanning direction. These features strongly suggest that a low-viscous super-cooled liquid (or low viscous melt) is formed in the laser-irradiated region. It is considered that laser irradiation gives a rapid temperature increase in the laser-irradiated part, consequently causing the formation of a low-viscous melt within an extremely short period. In the laser scanning experiments for the writing of crystal lines, therefore, it is considered that crystallization occurs through a cooling process from the high-temperature side to the low-temperature side. On the other
hand, usual crystallization of glass has been performed through the heating process from the low-temperature side to the high-temperature side. The above consideration (our model) for the cooling process from the high-temperature side to the low-temperature side. Process \( \odot \) in the laser scanning experiments for the writing of crystal lines, crystallization occurs through the cooling process from the high-temperature side to the low-temperature side. Process \( \oplus \): usual crystallization of glass occurs through the heating process from the low-temperature side to the high-temperature side. \( I \) and \( U \) are the nucleation and crystal growth rates, respectively.

**Fig. 13.** Model forNd:YAG laser-induced crystallization in glass. Process \( \odot \): in the laser scanning experiments for the writing of crystal lines, crystallization occurs through the cooling process from the high-temperature side to the low-temperature side. Process \( \oplus \): usual crystallization of glass occurs through the heating process from the low-temperature side to the high-temperature side. \( I \) and \( U \) are the nucleation and crystal growth rates, respectively.

**V. Conclusion**

Two techniques for laser-induced crystallization in glass were developed, i.e., REAH processing and TMAH processing, and were applied to some glasses for the patterning of non-linear optical crystals. It was clarified that these techniques are very effective in the writing of highly oriented crystal lines consisting of non-linear optical crystals such as \( \beta-BaB_2O_4 \), \( Sm_5Bi_4Bo_3 \), and \( Ba_2TiGe_2O_8 \). It was also clarified that it is possible to write two-dimensional crystal bending or curved lines by just changing the laser scanning direction. The mechanism of the laser-induced crystallization has been proposed. In particular, it was proposed that crystallization occurs through the cooling process from the high-temperature side to the low-temperature side in the laser scanning experiments for the writing of crystal lines. The development of new techniques for laser-induced crystallization indicates that the science and technology of the crystallization in glass are now in new phase, leading to new challenges.

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